0.8-1.0 GHz +36 dBm Power GaAs FET

MIMIX BROADBAND_{TM}

October 2009 - Rev 20-Oct-09 CFH2162-PI

Features

- X High Gain
- ★ +36 dBm Power Output
- Proprietary Power FET Process
- >45% Linear Power Added Efficiency
- ★ +33 dBm with 30 dBc Third Order Products

Description

The CFH2162-P1 is a high-gain, linear FET intended for driver amplifier applications in high-power systems, and output stage usage in medium power applications at power levels up to +36 dBm. The device is easily matched and provides excellent linearity at 4 Watts. Manufactured in Mimix's power FET process, this device is assembled in a power flange package.

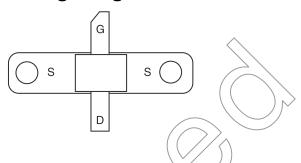
Specifications (TA = 25 °C)

The following specifications are guaranteed at room temperature in Mimix test fixture at 850 MHz.

Parameters	Conditions	Min	Тур	Max	Units
$V_d = 10V, I_d$	= 1100 mA (Quiescent)				^(/
P-1dB		36.0	37.0	_	dBm
G _{-1 dB}		19.0	20.0		dB
3rd Order Products (1)		30	35		фВç
Efficiency	@ P1dB		45	_)%)
$\overline{V_d} = 8V, I_d =$	= 1300 mA (Quiescent)		> _		
P _{-1dB}		((-	36.0	\ —	dBm
G _{-1 dB}		1	19.0	_	dB

Parameters	Conditions		Min	Тур	Max	Units
$\mathbf{g}_{\mathbf{m}}$	Vds = 2.0V, V	gs = 0V)—	1700	_	mS
I _{dss}	Vds = 2.0V, V	gs = 0V		2.8	_	A
V _p	Vds = 3.0V, K	ds = 65 mA	_	-1.8		Volts
BVGD	Igd = 6.5 mA		20	24	_	Volts
Θ _{JL} (2)	@150°C TCH	I	_	8	_	°C/W
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Package Diagram



Absolute Maximum Ratings

Drain-Source Voltage (Vds)	> 15V ⁽³⁾		
Gate-Source Voltage (Vgs)	-5V		
Drain Current (Ids)	Idss		
Continuous Dissipation (Pt)	10W		
Channel Temperature (Tch)	175 ℃		
Storage Temperature (Tstg)	-65 °C to +175 °C		

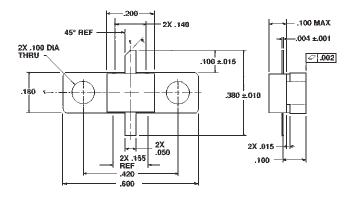
Notes:

- 1. Sum to two tones with 1 MHz spacing = 33 dBm.
- 2. See thermal considerations information.
- 3. Maximum potential difference across the device (Vd + Vg) cannot exceed 18V.

Applications

- X ISM Band Base Stations
- Cellular Base Stations
- Wireless Local Loop

Power Flange Package Physical Dimensions



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Ordering Information

The CFH2162-P1 power stage is available in a SOIC-8 surface mount package. Devices are available in tape and reel. Ordering part numbers are listed.

